

TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOSVI-H)

## TPCA8060-H

High-Efficiency DC-DC Converter Applications

Notebook PC Applications

Portable Equipment Applications

- Small footprint due to a small and thin package
- High-speed switching
- Small gate charge:  $Q_{SW} = 17\text{nC}$  (typ.)
- Low drain-source ON-resistance:  
 $R_{DS(ON)} = 2.8\text{ m}\Omega$  (typ.) ( $V_{GS} = 4.5\text{ V}$ )
- High forward transfer admittance:  $|Y_{fs}| = 141\text{ S}$  (typ.)
- Low leakage current:  $I_{DSS} = 10\text{ }\mu\text{A}$  (max) ( $V_{DS} = 30\text{ V}$ )
- Enhancement mode:  $V_{th} = 1.3\text{ to }2.3\text{ V}$  ( $V_{DS} = 10\text{ V}$ ,  $I_D = 1.0\text{ mA}$ )

### Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

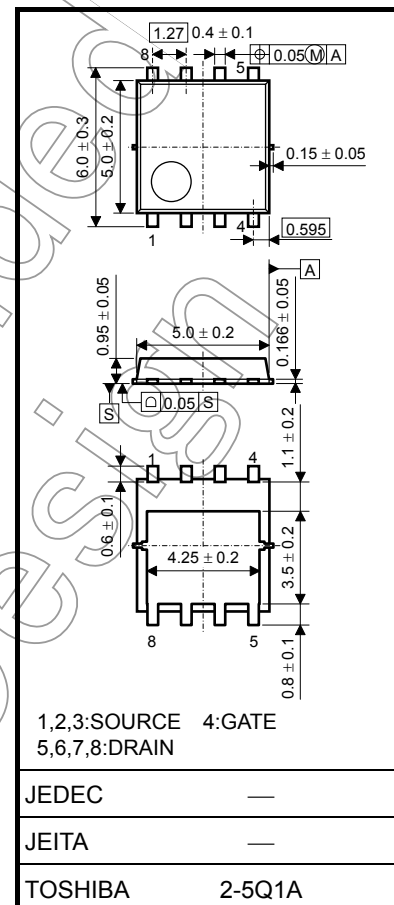
Characteristic		Symbol	Rating	Unit
Drain-source voltage		$V_{DSS}$	30	V
Drain-gate voltage ( $R_{GS} = 20\text{ k}\Omega$ )		$V_{DGR}$	30	V
Gate-source voltage		$V_{GSS}$	$\pm 20$	V
Drain current	DC (Note 1)	$I_D$	45	A
	Pulsed (Note 1)	$I_{DP}$	135	A
Drain power dissipation ( $T_c = 25^\circ\text{C}$ )		$P_D$	45	W
Drain power dissipation ( $t = 10\text{ s}$ ) (Note 2a)		$P_D$	2.8	W
Drain power dissipation ( $t = 10\text{ s}$ ) (Note 2b)		$P_D$	1.6	W
Single-pulse avalanche energy (Note 3)		$E_{AS}$	263	mJ
Avalanche current		$I_{AR}$	45	A
Repetitive avalanche energy ( $T_c = 25^\circ\text{C}$ ) (Note 4)		$E_{AR}$	3.53	mJ
Channel temperature		$T_{ch}$	150	$^\circ\text{C}$
Storage temperature range		$T_{stg}$	-55 to 150	$^\circ\text{C}$

Note: For Notes 1 to 4, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

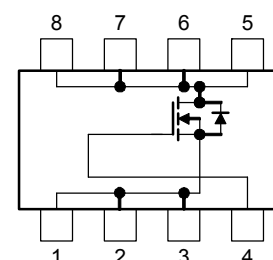
This transistor is an electrostatic-sensitive device. Handle with care.

Unit: mm



Weight: 0.069 g (typ.)

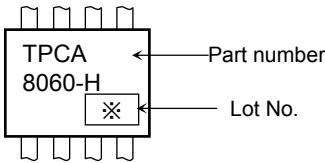
### Circuit Configuration



Thermal Characteristics

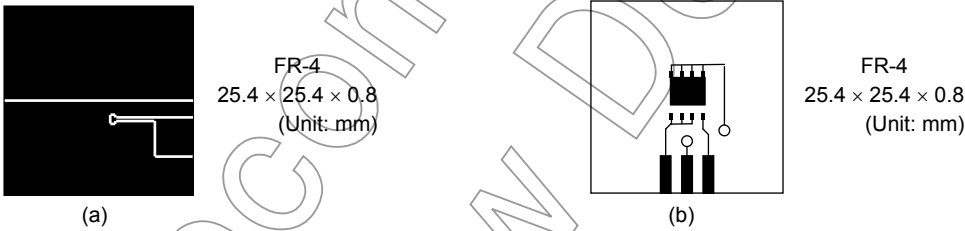
Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case ( $T_c = 25^{\circ}\text{C}$ )	$R_{th (ch-c)}$	2.78	$^{\circ}\text{C/W}$
Thermal resistance, channel to ambient ( $t = 10\text{ s}$ ) (Note 2a)	$R_{th (ch-a)}$	44.6	$^{\circ}\text{C/W}$
Thermal resistance, channel to ambient ( $t = 10\text{ s}$ ) (Note 2b)	$R_{th (ch-a)}$	78.1	$^{\circ}\text{C/W}$

Marking (Note 5)



Note 1: Ensure that the channel temperature does not exceed  $150^{\circ}\text{C}$ .

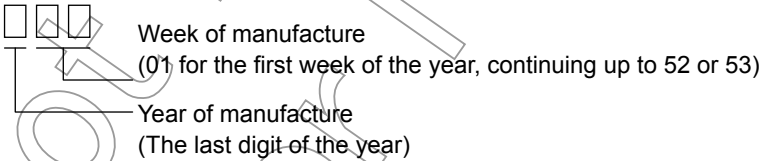
Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



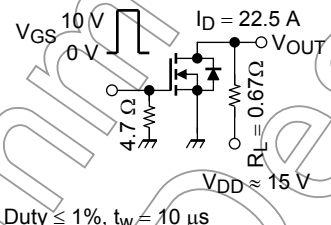
Note 3:  $V_{DD} = 24\text{ V}$ ,  $T_{ch} = 25^{\circ}\text{C}$  (initial),  $L = 100\text{ }\mu\text{H}$ ,  $R_G = 25\text{ }\Omega$ ,  $I_{AR} = 45\text{ A}$

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: \* Weekly code: (Three digits)

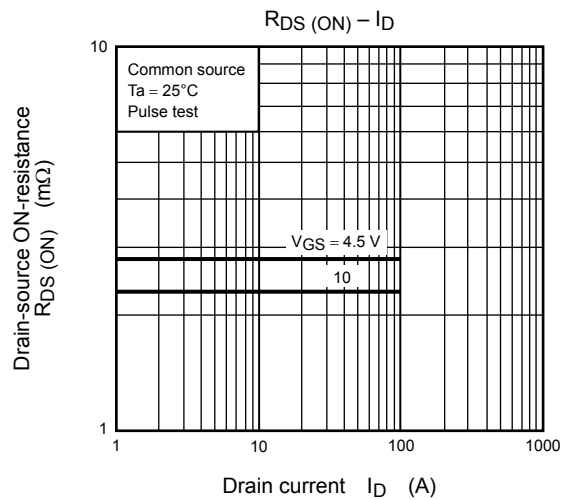
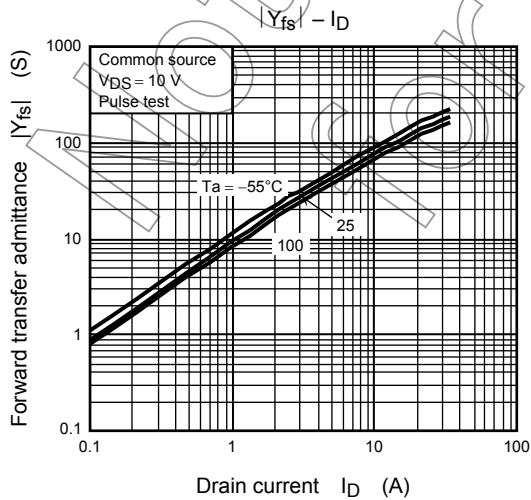
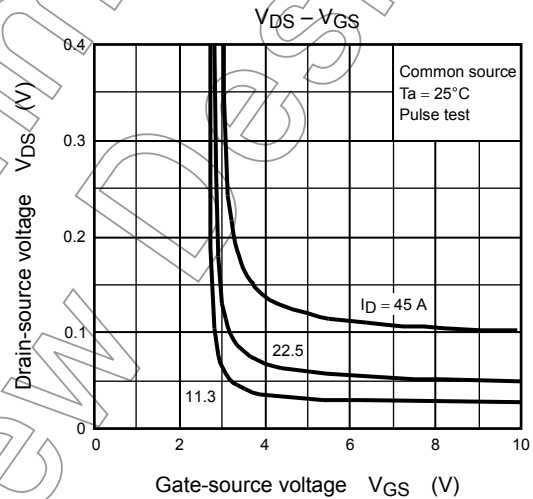
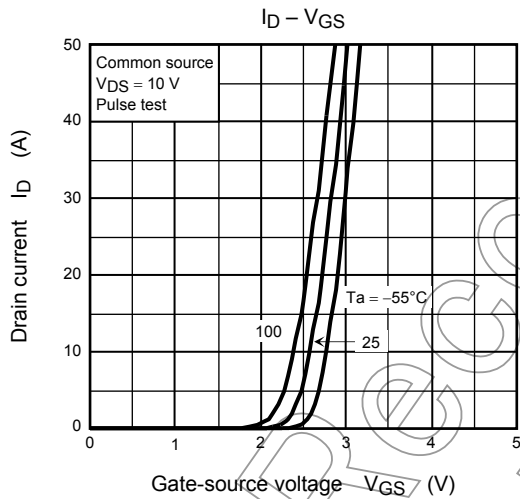
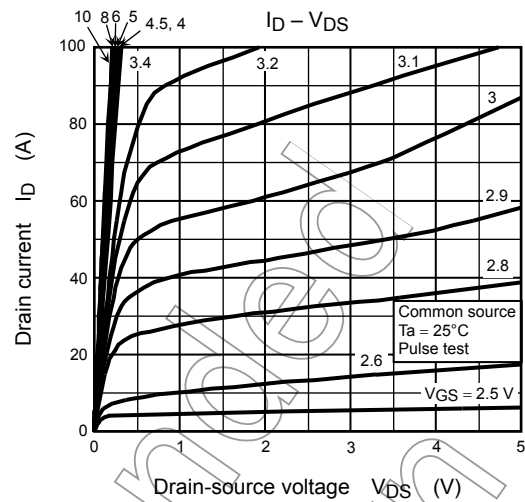
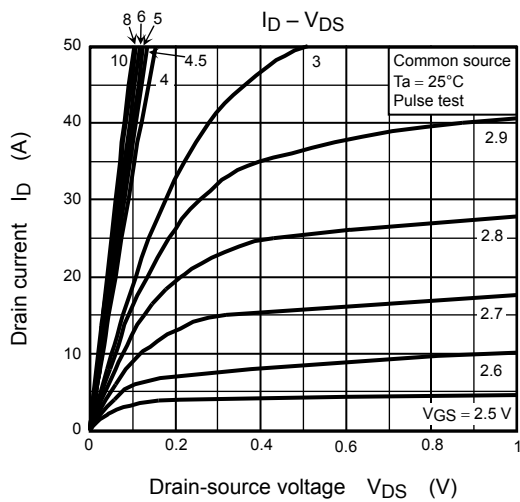


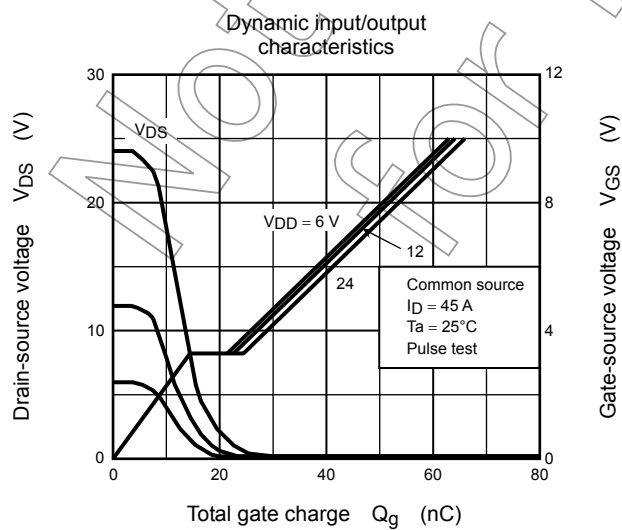
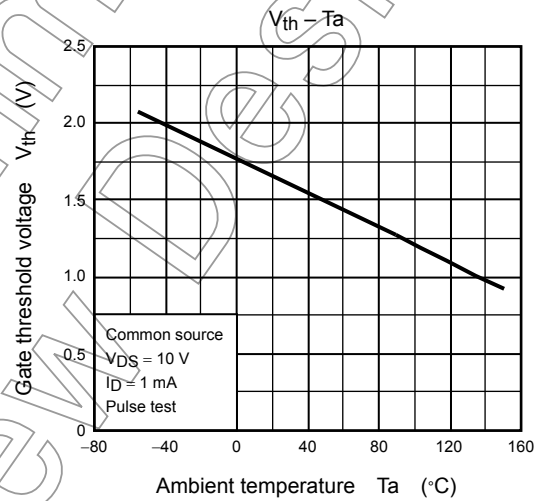
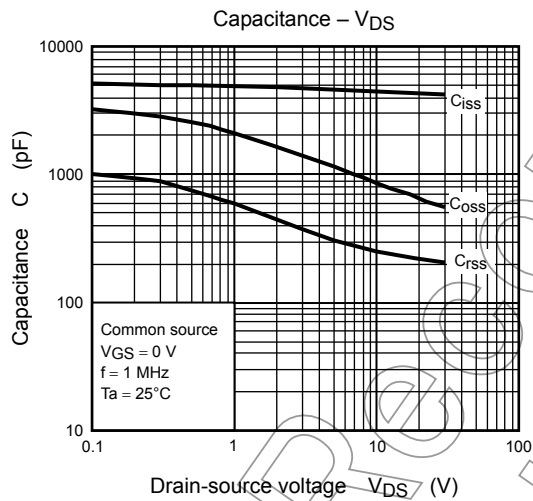
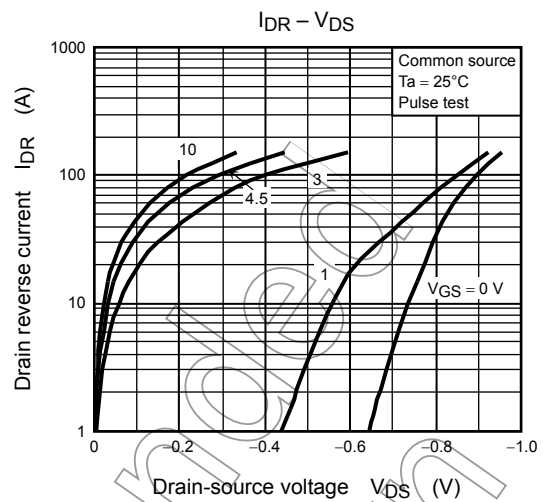
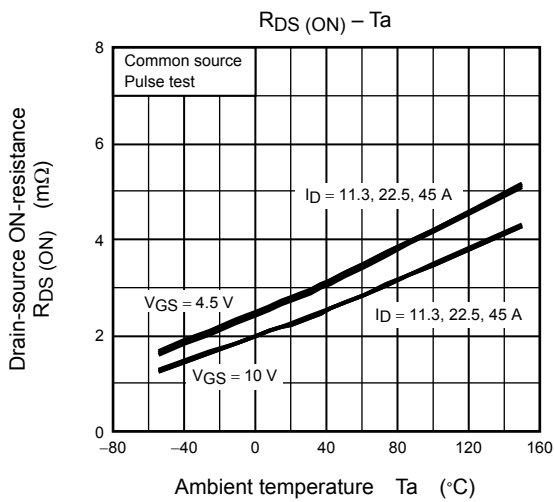
## Electrical Characteristics (Ta = 25°C)

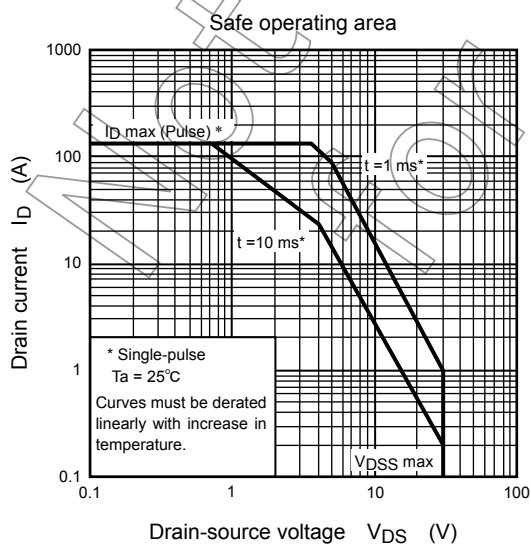
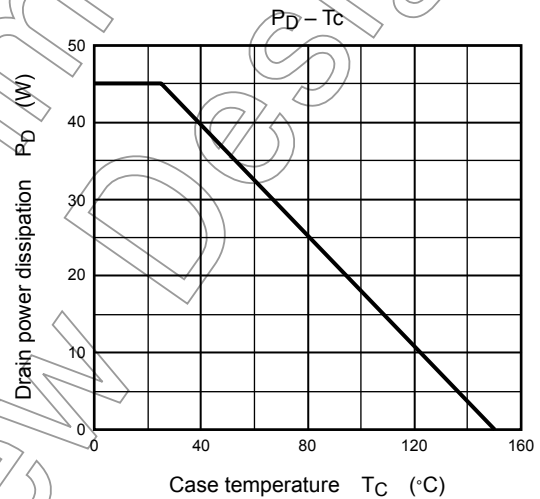
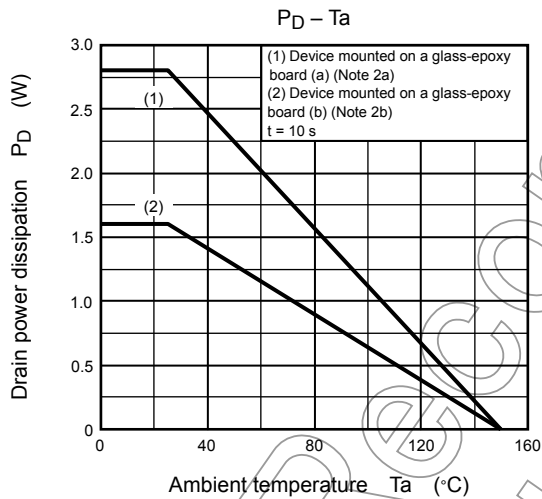
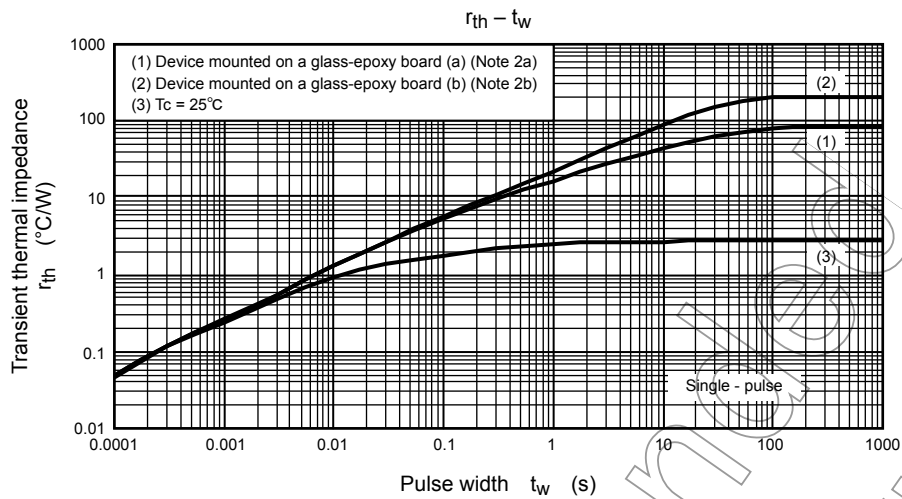
Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V	—	—	±100	nA
Drain cutoff current		I <sub>DSS</sub>	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V	—	—	10	μA
Drain-source breakdown voltage		V (BR) DSS	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	30	—	—	V
		V (BR) DSX	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = -20 V	15	—	—	
Gate threshold voltage		V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1.0 mA	1.3	—	2.3	V
Drain-source ON-resistance		R <sub>DS</sub> (ON)	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 22.5 A	—	2.8	3.9	mΩ
			V <sub>GS</sub> = 10 V, I <sub>D</sub> = 22.5 A	—	2.3	3.4	
Forward transfer admittance		Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 22.5 A	71	141	—	S
Input capacitance		C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	—	4600	6000	pF
Reverse transfer capacitance		C <sub>rss</sub>		—	290	460	
Output capacitance		C <sub>oss</sub>		—	860	—	
Gate resistance		r <sub>g</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	—	1.0	1.5	Ω
Switching time	Rise time	t <sub>r</sub>		—	5.1	—	ns
	Turn-on time	t <sub>on</sub>		—	16	—	
	Fall time	t <sub>f</sub>		—	8.5	—	
	Turn-off time	t <sub>off</sub>		—	52	—	
Total gate charge (gate-source plus gate-drain)		Q <sub>g</sub>	V <sub>DD</sub> ≈ 24 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 45 A	—	66	—	nC
			V <sub>DD</sub> ≈ 24 V, V <sub>GS</sub> = 5 V, I <sub>D</sub> = 45 A	—	34	—	
Gate-source charge 1		Q <sub>gs1</sub>	V <sub>DD</sub> ≈ 24 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 45 A	—	15	—	
Gate-drain ("Miller") charge		Q <sub>gd</sub>		—	9.9	—	
Gate switch charge		Q <sub>sw</sub>		—	17	—	

## Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Drain reverse current	Pulse (Note 1)	I <sub>DRP</sub>	—	—	—	135	A
Forward voltage (diode)		V <sub>DSF</sub>	I <sub>DR</sub> = 45 A, V <sub>GS</sub> = 0 V	—	—	-1.2	V







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